# **XBS053V15R-G**



ETR1607-003

# Schottky Barrier Diode, 500mA, 30V Type

#### **■**FEATURES

Forward Voltage : V<sub>F</sub>=0.40V (TYP.)

**Forward Current** : I<sub>F(AV)</sub>=500mA Repetitive Peak Reverse Voltage: V<sub>RM</sub>=30V

**Environmentally Friendly** : EU RoHS Compliant, Pb Free

#### **■**APPLICATIONS

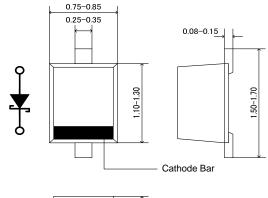
- Rectification
- Protection against reverse connection of battery

# ■ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT	
Repetitive Peak Reverse Voltage	VRM	30	V	
Reverse Voltage (DC)	VR	20	V	
Forward Current (Average)	<b>I</b> F(AV)	500	mA	
Non Continuous	IFSM	5	Α	
Forward Surge Current *1	IF5IVI	5	A	
Junction Temperature	Tj	125	°C	
Storage Temperature Range	Tstg	-55 <b>~</b> +150	°C	

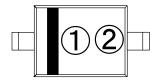
<sup>\*1:</sup> Non continuous high amplitude 60Hz half-sine wave.

#### ■ PACKAGING INFORMATION





# ■MARKING RULE



- ①: 2 (Product Number)
- 2: Assembly Lot Number

# ■PRODUCT NAME

PRODUCT NAME	DEVICE ORIENTATION		
XBS053V15R-G	SOD-523(Halogen & Antimony free)		
XBS053V15R	SOD-523		

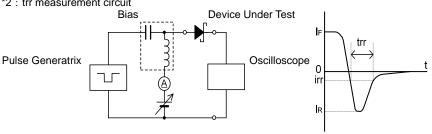
<sup>\*</sup> The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

#### ■ELECTRICAL CHARACTERISTICS

Ta=25°C

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
	STIVIBUL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Forward Voltage	VF1	I <sub>F</sub> =100mA	-	0.28	-	V
Forward voltage	VF2	I <sub>F</sub> =500mA	1	0.40	0.47	V
Reverse Current	lr	V <sub>R</sub> =20V	1	ı	100	μΑ
Inter-Terminal Capacity	Ct	V <sub>R</sub> =10V , f=1MHz	-	12	-	pF
Reverse Recovery Time *2	trr	I <sub>F</sub> =I <sub>R</sub> =10mA , irr=1mA	-	8	-	ns

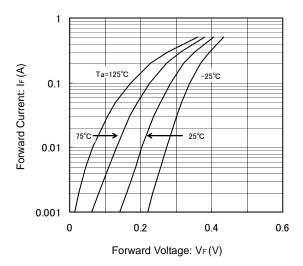
\*2 : trr measurement circuit



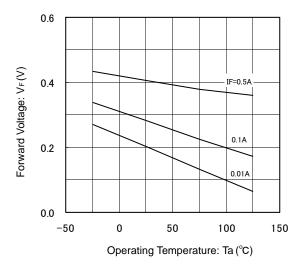
<sup>\*</sup> The device orientation is fixed in its embossed tape pocket.

### **■**TYPICAL PERFORMANCE CHARACTERISTICS

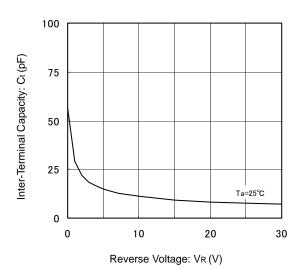
(1) Forward Current vs. Forward Voltage



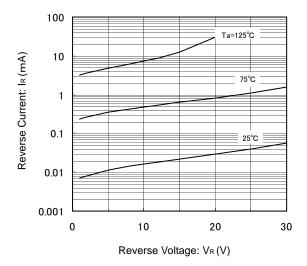
(3) Forward Voltage vs. Operating Temperature



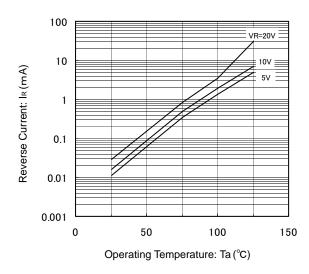
(5) Inter-Terminal Capacity vs. Reverse Voltage



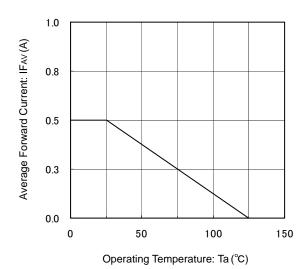
(2) Reverse Current vs. Reverse Voltage



(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature



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